

Description

The 74LVC2G14 is a dual Schmitt trigger inverter gate with standard push-pull outputs. The device is designed for operation with a power supply range of 1.65V to 5.5V. The inputs are tolerant to 5.5V allowing this device to be used in a mixed voltage environment. The device is fully specified for partial power down applications using I_{OFF}. The I_{OFF} circuitry disables the output preventing damaging current backflow when the device is powered down.

The gate performs the positive Boolean function:

$$Y = \bar{A}$$

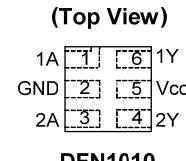
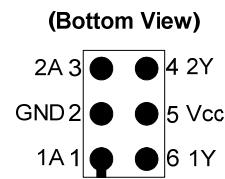
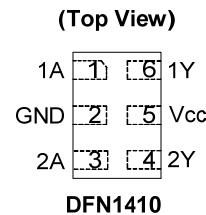
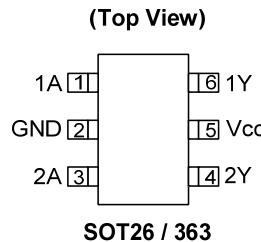
Features

- Wide Supply Voltage Range from 1.65V to 5.5V
- $\pm 24\text{mA}$ Output Drive at 3.0V
- CMOS low power consumption
- I_{OFF} Supports Partial-Power-Down Mode Operation
- Inputs accept up to 5.5V
- ESD Protection Tested per JESD 22
 - Exceeds 200-V Machine Model (A115)
 - Exceeds 2000-V Human Body Model (A114)
 - Exceeds 1000-V Charged Device Model (C101)
- Latch-Up Exceeds 100mA per JESD 78, Class I
- DFN1409 package designed as a direct replacement for chip scale packaging.
- Range of Package Options SOT26, SOT353, DFN1010, DFN1409 and DFN1410
- Leadless packages per JESD30E
 - DFN1410 denoted as X2-DFN1410-6
 - DFN1409 denoted as X2-DFN1409-6
 - DFN1010 denoted as X2-DFN1010-6
- **Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. "Green" Device (Note 3)**

Notes:

1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
2. See <http://www.diodes.com> for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and < 1000 ppm antimony compounds.

Pin Assignments



Applications

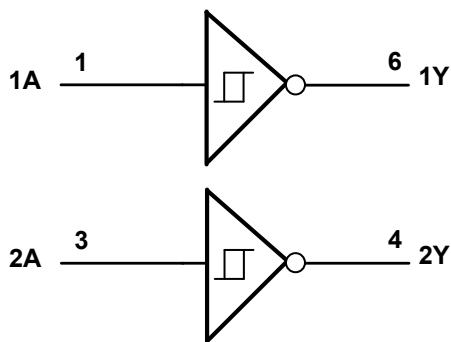
- Voltage Level Shifting
- General Purpose Logic
- Power Down Signal Isolation
- Wide array of products such as:
 - PCs, networking, notebooks, netbooks, tablets
 - Computer peripherals, hard drives, CD/DVD ROM
 - TV, DVD, DVR, set top box
 - Cell Phones, Personal Navigation / GPS
 - MP3 players, Cameras, Video Recorders

[Click here for ordering information, located at the end of datasheet](#)

Pin Descriptions

Pin Name	Pin NO.	Function
1A	1	Data Input
GND	2	Ground
2A	3	Data Input
2Y	4	Data Output
V _{CC}	5	Supply Voltage
1Y	6	Data Output

Logic Diagram



Function Table

Inputs	Output
A	Y
H	L
L	H

Absolute Maximum Ratings (Note 4) (@T_A = +25°C, unless otherwise specified.)

Symbol	Description	Rating	Unit
ESD HBM	Human Body Model ESD Protection	2	kV
ESD CDM	Charged Device Model ESD Protection	1	kV
ESD MM	Machine Model ESD Protection	200	V
V _{CC}	Supply Voltage Range	-0.5 to +6.5	V
V _I	Input Voltage Range	-0.5 to +6.5	V
V _O	Voltage applied to output in high impedance or I _{OFF} state	-0.5 to +6.5	V
V _O	Voltage applied to output in high or low state	-0.3 to V _{CC} +0.5	V
I _{IK}	Input Clamp Current V _I < 0	-50	mA
I _{OK}	Output Clamp Current V _O < 0	-50	mA
I _O	Continuous Output Current	-50	mA
—	Continuous Current Through V _{DD} or GND	±100	mA
T _J	Operating Junction Temperature	-40 to +150	°C
T _{STG}	Storage Temperature	-65 to +150	°C

Note: 4. Stresses beyond the absolute maximum may result in immediate failure or reduced reliability. These are stress values and device operation should be within recommend values.

Recommended Operating Conditions (Note 5) (@ $T_A = +25^\circ\text{C}$, unless otherwise specified.)

Symbol	Parameter		Min	Max	Unit
V_{CC}	Operating Voltage	Operating	1.65	5.5	V
		Data retention only	1.5	—	V
V_I	Input Voltage		0	5.5	V
V_O	Output Voltage		0	V_{CC}	V
I_{OH}	High-Level Output Current	$V_{CC} = 1.65\text{V}$	—	-4	mA
		$V_{CC} = 2.3\text{V}$	—	-8	
		$V_{CC} = 3\text{V}$	—	-16	
			—	-24	
		$V_{CC} = 4.5\text{V}$	—	-32	
I_{OL}	Low-Level Output Current	$V_{CC} = 1.65\text{V}$	—	4	mA
		$V_{CC} = 2.3\text{V}$	—	8	
		$V_{CC} = 3\text{V}$	—	16	
			—	24	
		$V_{CC} = 4.5\text{V}$	—	32	
$\Delta t/\Delta V$	Input transition rise or fall rate	$V_{CC} = 1.8\text{V} \pm 0.15\text{V}, 2.5\text{V} \pm 0.2\text{V}$	—	20	ns/V
		$V_{CC} = 3.3\text{V} \pm 0.3\text{V}$	—	10	
		$V_{CC} = 5\text{V} \pm 0.5\text{V}$	—	5	
T_A	Operating free-air temperature	—	-40	+125	°C

Note: 5. Unused inputs should be held at V_{CC} or Ground.

Electrical Characteristics (@ $T_A = +25^\circ\text{C}$, unless otherwise specified.)

Symbol	Parameter	Test Conditions	V_{cc}	-40°C to +85°C		-40°C to +125°C		Unit
				Min	Max	Min	Max	
V_{T+}	Positive-going input threshold voltage	—	1.8V	0.70	1.50	0.70	1.70	V
			2.3V	1.00	1.80	1.00	2.00	
			3V	1.30	2.20	1.30	2.40	
			4.5V	1.90	3.10	1.90	3.30	
			5.5V	2.20	3.60	2.20	3.80	
V_{T-}	Negative-going input threshold voltage	—	1.65V	0.25	0.90	0.39	1.10	V
			2.3V	0.40	1.15	0.25	0.87	
			3V	0.60	1.50	0.40	1.35	
			4.5V	1.00	2.00	0.60	1.70	
			5.5V	1.20	2.30	1.00	2.50	
ΔV_T	Hysteresis ($V_{T+} - V_{T-}$)	—	1.8V	0.15	1.00	0.37	1.20	μA
			2.3V	0.25	1.10	0.15	1.30	
			3V	0.40	1.20	0.40	1.40	
			4.5V	0.60	1.50	0.60	1.70	
			5.5V	0.70	1.70	0.70	1.90	
V_{OH}	High-Level Output Voltage	$I_{OH} = -100\mu\text{A}$	1.65V to 4.5V	$V_{cc} - 0.1$	—	$V_{cc} - 0.1$	—	V
		$I_{OH} = -4\text{mA}$	1.65V	1.2	—	0.95	—	
		$I_{OH} = -8\text{mA}$	2.3V	1.9	—	1.7	—	
		$I_{OH} = -16\text{mA}$	3V	2.4	—	1.9	—	
		$I_{OH} = -24\text{mA}$		2.3	—	2.0	—	
		$I_{OH} = -32\text{mA}$	4.5V	3.8	—	3.4	—	
V_{OL}	Low-Level Output Voltage	$I_{OL} = 100\mu\text{A}$	1.65V to 4.5V	—	0.1	—	0.10	V
		$I_{OL} = 4\text{mA}$	1.65V	—	0.45	—	0.70	
		$I_{OL} = 8\text{mA}$	2.3V	—	0.3	—	0.45	
		$I_{OL} = 16\text{mA}$	3V	—	0.4	—	0.60	
		$I_{OL} = 24\text{mA}$		—	0.55	—	0.80	
		$I_{OL} = 32\text{mA}$	4.5V	—	0.55	—	0.80	
I_I	Input Current	$V_I = 5.5\text{V}$ or GND	0 to 5.5V	—	± 5	—	± 20	μA
I_{OFF}	Power Down Leakage Current	V_I or $V_O = 5.5\text{V}$	0	—	± 10	—	± 20	μA
I_{CC}	Supply Current	$V_I = 5.5\text{V}$ or GND, $I_O = 0$	1.65V to 5.5V	—	10	—	40	μA

Package Characteristics (@ $T_A = +25^\circ\text{C}$, $V_{CC} = 3.3\text{V}$, unless otherwise specified.)

Symbol	Parameter	Package	Conditions	Min	Typ	Max	Unit
C_I	Input Capacitance	Typical of all packages	$V_{CC} = 3.3\text{V}$ $V_I = V_{CC} - \text{or GND}$	—	3.5	—	pF
θ_{JA}	Thermal Resistance Junction-to-Ambient	SOT26	(Note 6)	—	204	—	°C/W
		SOT363		—	371	—	
		X2-DFN1410-6		—	430	—	
		X2-DFN1409-6		—	450	—	
		X2-DFN1010-6		—	510	—	
θ_{JC}	Thermal Resistance Junction-to-Case	SOT26	(Note 6)	—	52	—	°C/W
		SOT363		—	143	—	
		X2-DFN1410-6		—	190	—	
		X2-DFN1409-6		—	225	—	
		X2-DFN1010-6		—	250	—	

Note: 6. Test condition for SOT26, SOT363, X2-DFN1410-6, X2-DFN1409-6 and X2-DFN1010 -6: Device mounted on FR-4 substrate PC board, 2oz copper with minimum recommended pad layout.

Switching Characteristics

$T_A = -40^\circ\text{C to } +85^\circ\text{C}$, $C_L = 30$ or 50pF (see Figure 1)

Parameter	From (Input)	TO (OUTPUT)	$V_{CC} = 1.8\text{V} \pm 0.15\text{V}$		$V_{CC} = 2.5\text{V} \pm 0.2\text{V}$		$V_{CC} = 3.3\text{V} \pm 0.3\text{V}$		$V_{CC} = 5\text{V} \pm 0.5\text{V}$		Unit
			Min	Max	Min	Max	Min	Max	Min	Max	
t_{pd}	A	Y	0.5	11.0	0.5	6.5	0.5	6.0	0.5	4.3	ns

$T_A = -40^\circ\text{C to } +125^\circ\text{C}$, $C_L = 30$ or 50pF (see Figure 1)

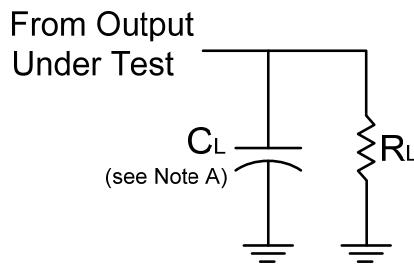
Parameter	From (Input)	TO (OUTPUT)	$V_{CC} = 1.8\text{V} \pm 0.15\text{V}$		$V_{CC} = 2.5\text{V} \pm 0.2\text{V}$		$V_{CC} = 3.3\text{V} \pm 0.3\text{V}$		$V_{CC} = 5\text{V} \pm 0.5\text{V}$		Unit
			Min	Max	Min	Max	Min	Max	Min	Max	
t_{pd}	A	Y	0.5	12.0	0.5	7.2	0.5	6.7	0.5	4.7	ns

Operating Characteristics

$T_A = +25^\circ\text{C}$

Parameter	Test Conditions	$V_{CC} = 1.8\text{V}$		$V_{CC} = 2.5\text{V}$		$V_{CC} = 3.3\text{V}$		$V_{CC} = 5\text{V}$		Unit
		Typ	Typ	Typ	Typ	Typ	Typ	Typ	Typ	
C_{pd}	Power dissipation capacitance	f = 10MHz	17	19	20	21	21	21	21	pF

Parameter Measurement Information



V _{CC}	Inputs		V _M	C _L	R _L
	V _I	t _r /t _f			
1.8V±0.15V	V _{CC}	≤2ns	V _{CC} /2	30 pF	1kΩ
2.5V±0.2V	V _{CC}	≤2ns	V _{CC} /2	30 pF	500Ω
3.3V±0.3V	3V	≤2.5ns	1.5V	50 pF	500Ω
5V±0.5V	V _{CC}	≤2.5ns	V _{CC} /2	50 pF	500Ω

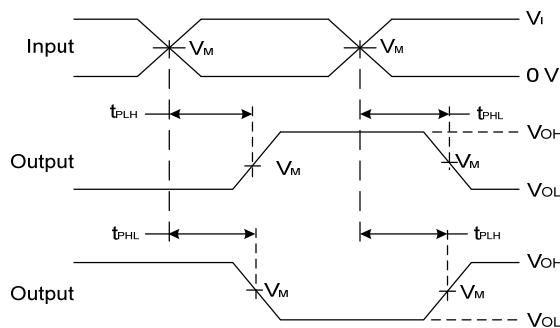
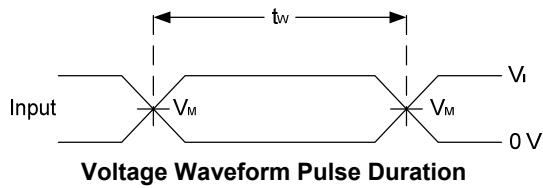


Figure 1. Load Circuit and Voltage Waveforms

Notes:

- A. Includes test lead and test apparatus capacitance.
- B. All pulses are supplied at pulse repetition rate ≤ 10 MHz.
- C. Inputs are measured separately one transition per measurement.
- D. t_{PLH} and t_{PHL} are the same as t_{PD}.

Ordering Information

74LVC2G 14 XXX - 7

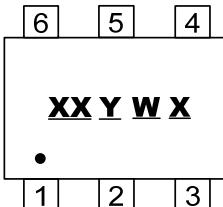
Logic Device	Function	Package	Packing
74 : Logic Prefix	14 : Inverter / Driver	W6 : SOT26	7 : Tape & Reel
LVC : 1.65 to 5.5V	Schmitt Trigger	DW : SOT363	
Family	Inputs	FW4 : X2-DFN1010-6	
2G : Two gate		FX4 : X2-DFN1409-6	
		FZ4 : X2-DFN1410-6	

Device	Package Code	Packaging (Note 7)	7" Tape and Reel	
			Quantity	Part Number Suffix
74LVC2G14W6-7	W6	SOT26	3000/Tape & Reel	-7
74LVC2G14DW-7	DW	SOT363	3000/Tape & Reel	-7
74LVC2G14FW4-7	FW4	X2-DFN1010-6	5000/Tape & Reel	-7
74LVC2G14FX4-7	FX4	X2-DFN1409-6	5000/Tape & Reel	-7
74LVC2G14FZ4-7	FZ4	X2-DFN1410-6	5000/Tape & Reel	-7

Note: 7. The taping orientation is located on our website at <http://www.diodes.com/datasheets/ap02007.pdf>

Marking Information

(1) SOT26, SOT363

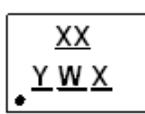


XX : Identification code
Y : Year 0~9
W : Week : A~Z : 1~26 week;
 a~z : 27~52 week; z represents
 52 and 53 week
X : A~Z : Internal Code

Part Number	Package	Identification Code
74LVC2G14W6	SOT26	Z5
74LVC2G14DW	SOT363	Z5

(2) X2-DFN1010-6, X2-DFN1409-6, X2-DFN1410-6

(Top View)

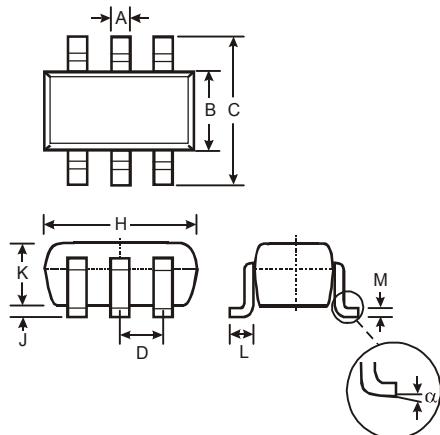


XX : Identification Code
Y : Year : 0~9
W : Week : A~Z : 1~26 week;
 a~z : 27~52 week; z represents
 52 and 53 week
X : A~Z : Internal code

Part Number	Package	Identification Code
74LVC2G14FW4	X2-DFN1010-6	Z5
74LVC2G14FX4	X2-DFN1409-6	X5
74LVC2G14FZ4	X2-DFN1410-6	Z5

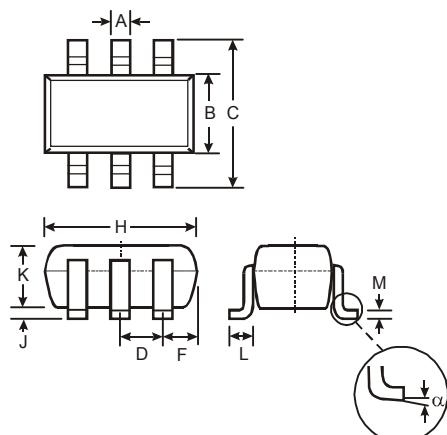
Package Outline Dimensions (All dimensions in mm.)

 Please see AP02002 at <http://www.diodes.com/datasheets/ap02002.pdf> for latest version.

(1) Package Type: SOT26


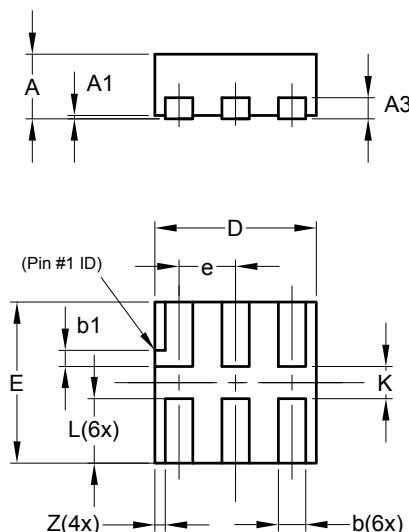
SOT26			
Dim	Min	Max	Typ
A	0.35	0.50	0.38
B	1.50	1.70	1.60
C	2.70	3.00	2.80
D	—	—	0.95
H	2.90	3.10	3.00
J	0.013	0.10	0.05
K	1.00	1.30	1.10
L	0.35	0.55	0.40
M	0.10	0.20	0.15
α	0°	8°	—

All Dimensions in mm

(2) Package Type: SOT363


SOT363			
Dim	Min	Max	Typ
A	0.10	0.30	0.25
B	1.15	1.35	1.30
C	2.00	2.20	2.10
D	0.65	Typ	
F	0.40	0.45	0.425
H	1.80	2.20	2.15
J	0	0.10	0.05
K	0.90	1.00	1.00
L	0.25	0.40	0.30
M	0.10	0.22	0.11
α	0°	8°	-

All Dimensions in mm

(3) Package Type: X2-DFN1010-6


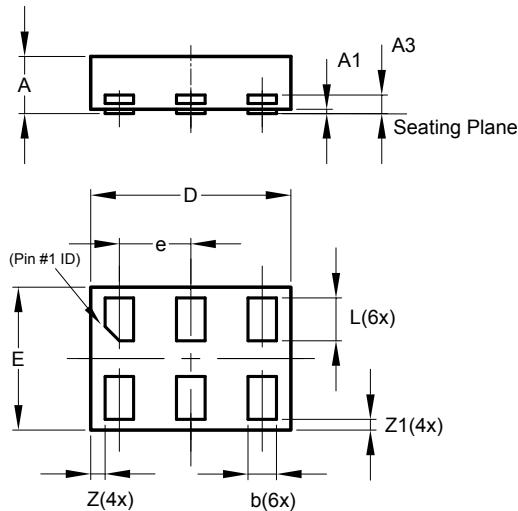
X2-DFN1010-6			
Dim	Min	Max	Typ
A	—	0.40	0.39
A1	0.00	0.05	0.02
A3	—	—	0.13
b	0.14	0.20	0.17
b1	0.05	0.15	0.10
D	0.95	1.05	1.00
E	0.95	1.05	1.00
e	—	—	0.35
L	0.35	0.45	0.40
K	0.15	—	—
Z	—	—	0.065

All Dimensions in mm

Package Outline Dimensions (cont.) (All dimensions in mm.)

Please see AP02002 at <http://www.diodes.com/datasheets/ap02002.pdf> for latest version.

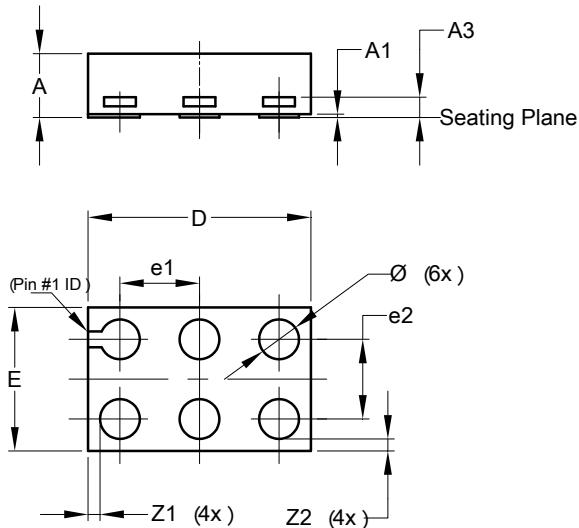
(4) Package Type X2-DFN1410-6



X2-DFN1410-6			
Dim	Min	Max	Typ
A	—	0.40	0.39
A1	0.00	0.05	0.02
A3	—	—	0.13
b	0.15	0.25	0.20
D	1.35	1.45	1.40
E	0.95	1.05	1.00
e	—	—	0.50
L	0.25	0.35	0.30
Z	—	—	0.10
Z1	0.045	0.105	0.075

All Dimensions in mm

(5) Package Type: X2-DFN1409-6 Chip Scale Replacement



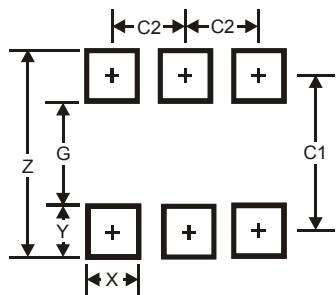
X2-DFN1409-6			
Dim	Min	Max	Typ
A	—	0.40	0.39
A1	0	0.05	0.02
A3	—	—	0.13
Ø	0.20	0.30	0.25
D	1.35	1.45	1.40
E	0.85	0.95	0.90
e1	—	—	0.50
e2	—	—	0.50
Z1	—	—	0.075
Z2	—	—	0.075

All Dimensions in mm

Suggested Pad Layout

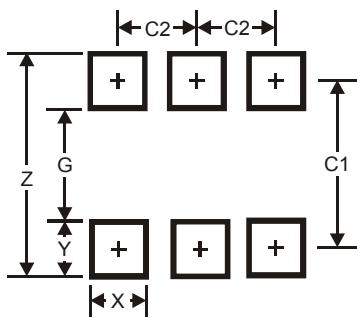
Please see AP02001 at <http://www.diodes.com/datasheets/ap02001.pdf> for the latest version.

(1) Package Type: SOT26



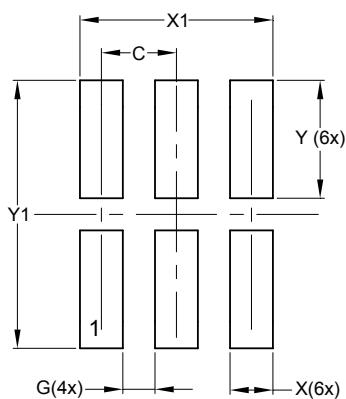
Dimensions	Value (in mm)
Z	3.20
G	1.60
X	0.55
Y	0.80
C1	2.40
C2	0.95

(2) Package Type: SOT363



Dimensions	Value (in mm)
Z	2.5
G	1.3
X	0.42
Y	0.6
C1	1.9
C2	0.65

(3) Package Type: X2-DFN1010-6

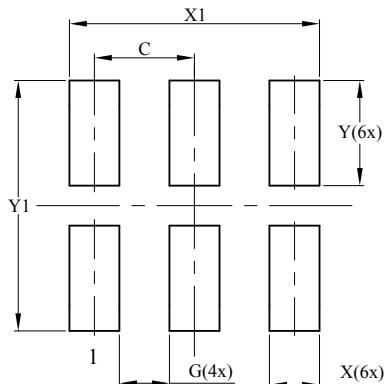


Dimensions	Value (in mm)
C	0.350
G	0.150
X	0.200
X1	0.900
Y	0.550
Y1	1.250

Suggested Pad Layout (cont.)

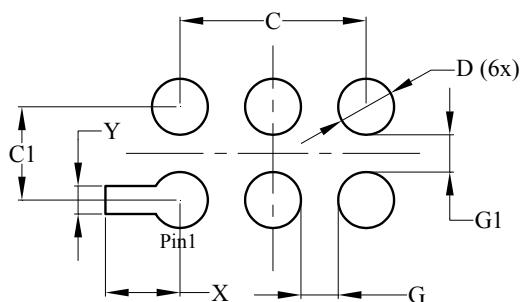
Please see AP02001 at <http://www.diodes.com/datasheets/ap02001.pdf> for the latest version.

(4) Package Type X2-DFN1410-6



Dimensions	Value (in mm)
C	0.500
G	0.250
X	0.250
X1	1.250
Y	0.525
Y1	1.250

(5) Package Type: X2-DFN1409-6 Chip Scale Replacement



Dimensions	Value (in mm)
C	1.000
C1	0.500
D	0.300
G	0.200
G1	0.200
X	0.400
Y	0.150

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